# 2SD1366

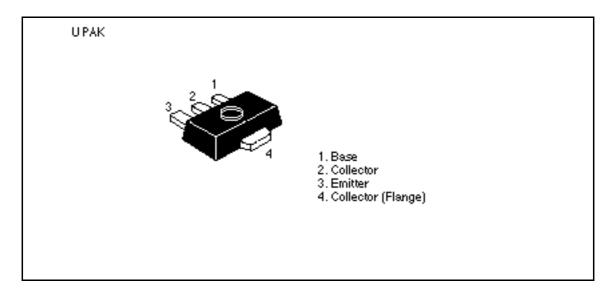
## Silicon NPN Epitaxial

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#### **Application**

Low frequency power amplifier

#### **Outline**





## **2SD1366**

### **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{\text{CBO}}$	25	V
Collector to emitter voltage	$V_{\text{CEO}}$	20	V
Emitter to base voltage	$V_{EBO}$	5	V
Collector current	I <sub>c</sub>	1	А
Collector peak current	i <sub>C(peak)</sub> *1	1.5	А
Collector power dissipation	P <sub>C</sub> *2	1	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW 10 ms, Duty cycle 20%.

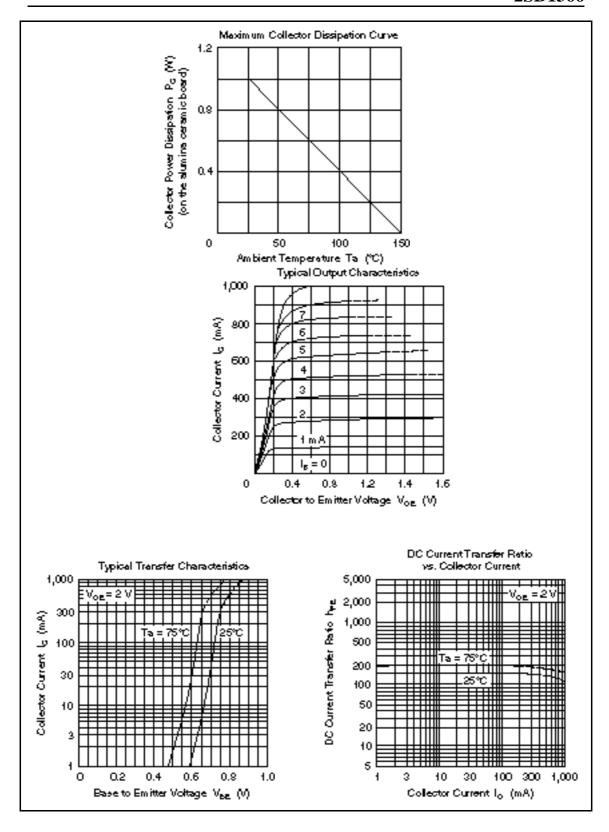
2. Value on the alumina ceramic board (12.5  $\times$  20  $\times$  0.7 mm)

## **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

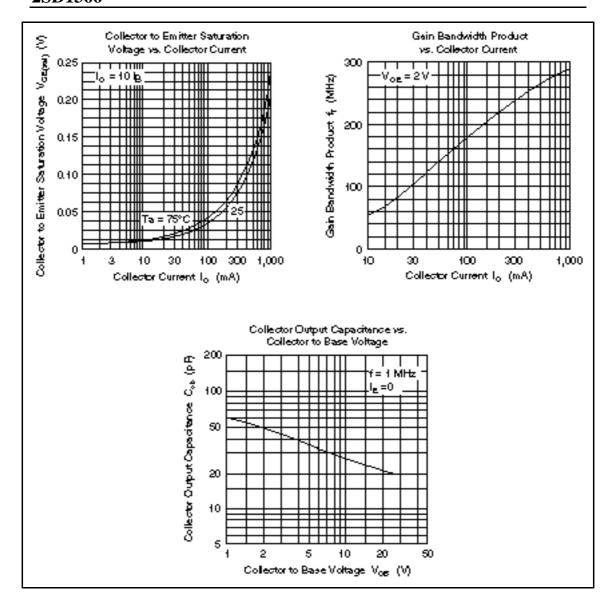
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	25	_	_	V	$I_{c} = 10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	20	_	_	V	$I_{\text{C}} = 1 \text{ mA}, R_{\text{BE}} =$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	_	_	V	$I_{E} = 10 \ \mu A, \ I_{C} = 0$
Collector cutoff current	I <sub>CBO</sub>	_	_	0.1	μΑ	$V_{CB} = 20 \text{ V}, I_{E} = 0$
Emitter cutoff current	I <sub>EBO</sub>	_		0.1	μA	$V_{EB} = 4 \text{ V}, I_{C} = 0$
DC current transfer ratio	h <sub>FE</sub> *1	85	_	240		$V_{CE} = 2 \text{ V}, I_{C} = 0.5 \text{ A}, \text{ Pulse}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	0.15	0.3	V	$I_{c} = 0.8 \text{ A}, I_{B} = 0.08 \text{ A}, \text{ Pulse}$
Base to emitter saturation voltage	$V_{BE(sat)}$	_	0.9	1.0	V	$I_{\rm C} = 0.8 \text{ A}, I_{\rm B} = 0.08 \text{ A}, \text{ Pulse}$
Gain bandwidth product	f <sub>T</sub>	_	240	_	MHz	$V_{CE}$ = 2 V, $I_{C}$ = 0.5 A, Pulse
Collector output capacitance	Cob	_	22	_	pF	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$

Note: 1. The 2SD1366 is grouped by  $h_{\mbox{\tiny FE}}$  as follows.

Mark	AA	AB
h <sub>FE</sub>	85 to 170	120 to 240



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